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Cite this: DOI: 10.1039/c0xx00000x

www.rsc.org/xxxxx

# **ARTICLE TYPE**

# UV-patternable nanocomposite containing CdSe and PbS quantum dots as miniaturized luminescent chemo-sensors

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s Received (in XXX, XXX) Xth XXXXXXXX 2013, Accepted Xth XXXXXXXX 2013 First published on the web Xth XXXXXXXX 2013 DOI: 10.1039/b000000x

In this study, a novel multifunctional hybrid polymer-based luminescent material especially formulated for photolithography was developed for the fabrication and testing as miniaturized chemosensor. This nanocomposite is formulated with either luminescent <sup>10</sup> CdSe (for the visible) or PbS (for the near-IR) colloidal QDs embedded in a polyisoprene-based photoresist (PIP). We checked the sensing capability of the nanocomposite by exposing 1 cm<sup>2</sup> CdSe nanocomposite patterns to vapours of some analyte solutions like 2-mercaptoethanol (MET) and ethylenediamine (EDA). The transduction mechanism of the sensor is based on changes of the QD photoluminescence (PL) when molecules are adsorbed on the QD surface. Since the polymer used suffers from swelling during the development step of the sensor fabrication, the diffusion of the analytes through the matrix is rather high. As a result,

<sup>15</sup> the sensor response to the analyte-QD interactions is considerably short and sensitive. We observed shorter sensor response times to MET than EDA. Moreover, we found a limit of detection of MET and EDA of 0.1 pg and 10 ng respectively. The linear detection range for MET and EDA was determined to be over an analyte concentration of 6 and 5 orders of magnitude respectively. We also tested the PbS-based nanocomposite response to MET and EDA and found very different response. Whereas EDA quenches the PbS PL, exposure to MET molecules resulted in a 6.5-fold enhancement of the PL. The mechanisms of the <sup>20</sup> observed effects are discussed in detail.

# Introduction

The role of nanocience in analytical science has been greatly established for the development of (bio)chemical sensors with <sup>25</sup> enhanced performance. The desing of low-cost, easy-tofabricate and portable analytical devices with a low limit of

- detection (LOD), good selectivity, high sensitivity and short response time are being insistently demanded.<sup>1,2,3</sup> Part of that success has been made possible by the use of nanomaterials. <sup>30</sup> In particular, (bio)chemical sensors based on fluorescent
- quantum dots (QDs) have attracted intense interest because of their excellent optical and electronic properties over the routinely employed fluorescent organic dyes.<sup>4,5</sup> These properties include size-tunable light emission over a wide
- <sup>35</sup> range of energies, high photoluminescence quantum yield (PL QY), narrow emission line width, and good solution processability.<sup>6</sup> Additionally, the physicochemical stability of QDs, their extremely large surface area, as well as the posibility of functionalizating their surface by conjugation <sup>40</sup> with the appropriate molecules make them very attractive
- nanomaterials for ultrasensitive sensors with the possibility of multiplex (bio)chemical detection.<sup>7</sup>

The transduction mechanism of QD-based sensors is supported on the changes on the PL QY by the 45 physicochemical interactions occurring at the QD surface. Since the PL of QDs is strongly affected by surface defects that can affect the recombination of electrons and holes analyte binding on the QD may lead to either quenching or enhancement of the PL.<sup>5,8</sup>

50 A challenging step towards the development of QD-based (bio)chemical sensors is to efficiently transfer colloidal QDs to solid-state support structures preserving as far as possible all their optical properties.<sup>9,10</sup> In this context, some approaches to solid-state QD sensors have been recently reported. The 55 most common approach to QD sensor consists of depositing colloidal QD from solution onto a substrate to form a film by different desposition techniques (dropcasting, spin-coating or Dr. Blading). Bakar et al. developed a sensor based on ZnCdSe fabricated by dropcasting for sensing pesticide <sup>60</sup> molecules.<sup>11</sup> It was observed that the PL intensity of the films was quenched by the presence of the pesticide molecules adsorbed on the QD surface. Other authors used a similar approach to develop PL temperature sensors with high sensitivities and resolution.<sup>12,13</sup> Nevertheless, all these sensors 65 based on QD-solids often exhibit very soft films with poor mechanical propecties and low stability in hot or oxygenated environments leading to the formation of trap states, QD oxidation, and the subsequent deterioration of the QD lattice.

To overcome these drawbacks, a very promising approach 70 towards QD-based sensors with high sensitivity, high stability as

well as low cost consists of embedding the luminescent QDs into polymeric matrices to form a nanocomposite. This type of hybrid materials has drawn significant attention from researchers over the last decade.<sup>14,15</sup> Here, incorporation of QDs into a host

- <sup>5</sup> polymer matrix results in the design of novel nanocomposite materials with a combination of the properties of the constituent materials and even new ones.<sup>16</sup> Moreover, the fact that the QD surface can be optimally modified by appropriate ligands allows to obtain optimal dispersion of the QDs inside the polymeric
- <sup>10</sup> matrix, which is one of the key points to achieve high transparency and high luminescence efficiency required for this kind of QD-based materials.<sup>17</sup> Polymers are ideal host materials for device fabrication because they show a very broad range of properties such as flexibility, lightweight, low cost and can be
- <sup>15</sup> processed as a thin film. One of the major trends in the area of (bio)chemical sensors is directed towards their miniaturization.<sup>18</sup> This is a critical aspect to obtain higher sensitivity, lower limit of detection, and faster binding rates,<sup>19</sup> and paves the road to develop lab-on-chip systems. The use of polymeric host matrices
- <sup>20</sup> having lithographic capability provides the possibility of device fabrication and miniaturization by means of conventional patterning techniques such as electron beam lithography or photolithography.<sup>16,20,21</sup>

Some approaches to (bio)chemical sensors based on QD-based

- <sup>25</sup> nanocomposites have been recently published. For instance, Potyrailo and co-workers investigated the response of different-size CdSe QDs incorporated in a variety of polymers matrices to vapours of several organic solvents with different polarity.<sup>22</sup> Besides, other authors have also proposed the use
- <sup>30</sup> of CdSe QDs with different surface functional groups embedded in polymethylmethacrylate (PMMA)<sup>23</sup> to sense volatile compounds such as amines,<sup>24</sup> aromatic hydrocarbons,<sup>25,26</sup> or ethanol<sup>27</sup> as proof of concept. However, the poterntial patterning capability of these QD-based <sup>35</sup> nanocomposite sensors have not been explored yet, which is
- the first step towards miniaturization and device fabrication. Only some QD-nanocomposite approaches show the possibility of miniaturization by conventional and large scale patterning methods,<sup>28,29</sup> but, to the best of our knowledge, 40 application of such QD-based patterns for sensing has not
- been reported in the literature.

In this work, we have developed a novel multifunctional hybrid polymer-based luminescent material especially formulated for photolithography and tested as miniaturized <sup>45</sup> chemosensor. This nanocomposite is formulated with either luminescent CdSe (for the visible) or PbS (for the near-IR) colloidal QDs embedded in a polyisoprene-based photoresist (PIP). The resulting nanocomposite combines the extraordinary optical properties of the QDs with the <sup>50</sup> lithographic characteristics of the resist matrix. Both the

- optical properties of QDs and the lithographic performance of the photoresist are preserved after their incorporation of QDs into the photoresist. We checked the sensing capability of this QD-PIP nanocomposite using 1 cm<sup>2</sup> square patterns as a
- 55 disposable gas sensor by monitoring the PL intensity upon exposure to 2-mercaptoethanol (MET) and ethylenediamine

(EDA) using two types of QDs: CdSe and PbS. The transduction mechanism of the sensor is based on changes of the QD photoluminescence (PL) when molecules are adsorbed <sup>60</sup> on the QD surface. CdSe-PIP pattern sensor showed a decay of PL when exposed different amounts of MET and EDA in vapour and found a LOD around 10<sup>-3</sup> ng/L and 270 ng/L respectively. From the calibration curve, we determined that the binding affinity of MET to CdSe-PIP is around four orders

<sup>65</sup> of magnitude higher than that of EDA. We also observed a linear sensing behaviour within a broad concentration range, which allows us to use CdSe-PIP as quantitative sensor for MET and EDA.

Furthermore, PbS-PIP nanocomposite shows different sensor <sup>70</sup> responses depending on the target analyte: whereas exposure of PbS-PIP sensor to EDA led to quenching of the QD PL, exposure to MET molecules resulted in a 6.5-fold enhancement of the PL intensity. This different response of CdSe and PbS QDs to MET can be explained by the <sup>75</sup> difference in the energy of these QDs valence band top with respect to the redox level of the thiol molecule.

In conclusion, these results demonstrate that a fully disposable sensing platform technology can be developed using this novel QD-PIP luminescent nanocomposite, which may also form the basis for the development of miniaturized chemosensors, which may be of interest for several fields such as food industry, environmental monitoring, and health.

# Experimental

Materials and apparatus. A commercially available negative <sup>85</sup> bisazide-cyclized polyisoprene photoresist, o-xylene, 2mercaptoethanol (MET) and ethylenediamine (EDA) were purchased from Aldrich and used without further purification. Cadmium oxide powder (CdO), lead oxide powder (PbO), trioctylphosphine (TOP), bis(trimethylsilylsulfide) (TMS), <sup>90</sup> selenium powder, octadecene (ODE), oleic acid (OA), anhydrous toluene, acetone, methanol were also purchased from Sigma-Aldrich.

**Synthesis of CdSe QDs.** Highly luminescent CdSe QDs were synthesized by conventional synthesis route based on hot <sup>30</sup> injection method.<sup>30</sup> Briefly, a mixture of CdO (5 mmol), oleic acid (30 mmol), and ODE was heated and distilled in vacuum at 120°C for 30 minutes. Subsequently, this mixture was heated up to 250°C for complete dissolution of precursors under N<sub>2</sub>. Then, the transparent solution of Se (3.2 mmol) and TOP (16 mmol) <sup>100</sup> was injected swiftly at 250 °C and reacted for 5 min. Finally, the QDs were purified by several successive precipitation and redispersion steps with a mixture of acetone and methanol and redispersed in o-xylene with a concentration of 20 mg / mL.

**Synthesis of PbS QDs.** For the synthesis of PbS colloidal QDs, <sup>105</sup> the lead precursor was prepared by pumping in vacuum the mixture of PbO (4 mmol) and oleic acid (63 mmol) in ODE at 120°C for 30 minutes to remove water. The stock solution of the sulfur precursor was prepared by mixing TMS (1 mmol) in ODE (10 mL) and injected rapidly into the reaction flask containing the lead precursor at 160°C. The resulting PbS QDs were purified by three successive precipitation and redispersion steps using acetone and toluene, respectively. Finally, the QDs were dispersed in o-xylene with a concentration of 20 mg / mL.

- <sup>5</sup> QD-PIP nanocomposite preparation and device fabrication. Nanocomposites were prepared by dispersion of the oleatecapped QDs in the photoresist, both dissolved in o-xylene. We formulated different nanocomposite solutions by varying the amounts of both QD and photoresist adding the corresponding
- <sup>10</sup> volume of solvent to obtain the same thickness. The resulting nanocomposite solution was mixed under stirring for 15 min to obtain a homogeneous dispersion. Prior to the fabrication process, BK7 glasses used as substrates were rinsed with isopropanol and baked at 120 °C for 20 min. Then, the films were prepared by
- <sup>15</sup> spin-coating the nanocomposite solution on the substrate at 2000 rpm for 30 s. In order to achieve good adhesion of the nanocomposite to the substrate, the films were soft-baked at 82 °C for 20 min to remove the residual solvent and volatile components. The resulting films were about 1 μm thick. The
- <sup>20</sup> samples were then exposed to UV light at 200 mW/cm<sup>2</sup> for 5 s in a Süss Microtec MJB4 mask aligner using a photomask consisting of features with different shapes and sizes. Afterwards, development of the structures was performed by spraying the developer onto the samples during 10-20 s followed by a rinsing
- <sup>25</sup> several times with isopropyl alcohol and drying with compressed air. Finally, a hard-bake at 120 °C for 10 min was carried out to remove residual solvents and to enhance the chemical stability of the layer.

**Characterization techniques.** Optical absorbance spectra of the <sup>30</sup> nanocomposite films containing CdSe QDs were recorded at room temperature using an ultraviolet–visible Perkin-Elmer Lambda 20 spectrophotometer. In case of PbS QDs the absorbance spectra of both the colloidal solution as well as nanocomposite films were measured with the aid of an IR Ocean

- <sup>35</sup> Optics spectrograph. Photoluminescence spectra were obtained at room temperature and under air atmosphere upon excitation of samples with a CW GaN laser (404 nm) or DSPP diode laser (533 nm). In both cases the excitation power was fixed to be around 15 kW/cm<sup>2</sup>. Quantum yield of PL for CdSe QDs was determined
- <sup>40</sup> using an integrated sphere (Hamamatsu model C9920-0). Transmission electron microscopy (TEM) studies of the QDs were carried out at an accelerating voltage of 100kV using a JEOL 1010 microscope.

Analyte sensing protocol. The sensing capability of the QD-PIP <sup>45</sup> nanocomposites was evaluated using 1 cm<sup>2</sup> square patterns. These patterns were exposed to the vapours of 9 mL of different aqueous solution concentrations of MET and EDA in a closed vessel of 130 mL in a thermostatic bath at 25 °C. Each spectrum was registered for different times once the liquid-vapour <sup>50</sup> equilibrium was restored after closing the vessel. We used a positioning system that enables the measurement in the same position of the nanocomposite pattern. Thus, accurate and representative values of PL intensity could be obtained.

# **Results and Discussion**

## 55 Optical properties of the QD-PIP nanocomposite.

This work aims at the development of a novel OD-polymer hybrid material that combines the extraordinary optical properties of the ODs with the lithographic characteristics of the chosen host matrix. After proper formulation of the nanocomposite, we firstly 60 examined the optical absorption and emission properties of the QD colloidal solution, the photoresist, and the nanocomposite thin film. Optical properties of QDs strongly depend on both their size and composition. Fig. 1 shows absorption spectra of colloidal CdSe QDs in o-xylene and in the nanocomposite. The absorption 65 peak at 572 nm observed for colloidal suspension corresponds to the lowest energy exciton state of the CdSe QDs, whereas a second exciton state is observed around 475 nm. The absorbance of the colloidal CdSe QDs increases continuously to shorter wavelengths and is negligible beyond 630 nm. The average size 70 of the CdSe QDs determined by transmission electron microscopy was about 2.5 nm (Fig. S3, ESI<sup>†</sup>). This experimental value is in good agreement with that determined on the basis of the energy of the CdSe exciton with use of well-known empirical formulas.31,32

<sup>75</sup> When CdSe QDs are embedded into the photoresist, the exciton peak appears at the same wavelength as in solution (the CdSe QD peak is visible in the composite absorption spectrum as a weak shoulder because the QDs concentration in polymer was much lower than in case of the solution). This indicates that diameter <sup>80</sup> and size distribution of CdSe QDs remain unchanged during the whole fabrication process. The nanocomposite absorption band centered at 355 nm belongs to the bisazide photoactive compound of the negative photoresist (Fig. S1, ESI†). Typically, polyisoprene-based photoresist formulation consists of a 9.7 wt.

<sup>85</sup> % of cyclized polyisoprene and 0.3 wt. % of bisazide photoactive compound in o-xylene. Upon exposure to light, the photosensitive molecules strongly absorb the UV (320-380 nm) light and undergo several photoreactions to crosslink the polymer chain.



**Figure 1.** a) Absorbance spectra of CdSe QDs in o-xylene (red line) and embedded in the PIP-based photoresist (blue line). Inset: TEM image of 5 CdSe QDs with an average size of 2.5 nm. b) Emission spectra of CdSe QDs in o-xylene and the in the nanocomposite film upon excitation at 532 nm. Inset: Emission of the bisazide molecule contained in the photoresist film upon excitation at 404 nm.

Fig. 1b shows the emission spectra of the colloidal CdSe QDs in 10 o-xylene solution and in the nanocomposite thin film measured upon excitation at 532 nm to avoid excitation of the photoresist. Emission of the photoresist was also measured upon excitation at 404 nm and is shown in the inset in Fig. 1b as a very broad emission with a maximum at around 515 nm (Fig. S2, ESI<sup>†</sup>). The

- <sup>15</sup> emission band of colloidal CdSe in solution has a maximum around 586 nm with 43 nm FWHM. The PL QY was 30%. The narrow FWHM of the fluorescence spectra and the reasonably high QY achieved indicate the absence of surface traps due to a good passivation of the QD surface by means of oleate ligands.
- <sup>20</sup> This is an important point because surface defects on QDs usually result in a significant decrease in their fluorescence QY. When QDs are embedded into the photoresist, the emission is blue shifted to 570 nm and has a FWHM of 41 nm. The blue shift is most likely a result of a decrease of refractive index effective
- <sup>25</sup> value in the QDs environment due to a porous character of the polymer matrix. Therefore, the emission spectrum of the nanocomposite has a shape similar to the QDs spectrum obtained in solution indicating that the QDs embedded into the resist matrix are well dispersed without aggregation.

- <sup>30</sup> To demonstrate wide capabilities of the nanocomposite, the photoresist was also formulated with near-infrared luminescent QDs from the IV-VI group, PbS. Because these QDs are also capped with oleate, they show good solubility in o-xylene and can be easily dispersed into the photoresist. Fig. 2a shows the
- <sup>35</sup> TEM image (inset) and optical properties of colloidal PbS QDs used for the fabrication of the PbS-PIP nanocomposite. From TEM images we observe spherical PbS QDs with a mean diameter of 3.2 nm (Fig. S4, ESI<sup>†</sup>). Colloidal PbS QDs in o-xylene show a well-defined excitonic peak in absorption centred <sup>40</sup> at 960 nm and an emission band with a maximum at 1050 nm
- (Fig. 3b). For the PbS-based nanocomposite, excitonic peak maximum is also located at 960 nm, whereas the PL band maximum is at 1000 nm. Characterization of the absorption of the PbS QDs in the nanocomposite could not be clearly recorded <sup>45</sup> because of the low QD concentration into the PIP matrix and the low sensitivity of the InGaAs photodetector used in the setup.



**Figure 2.** a) Absorbance spectra of PbS QDs in o-xylene. Inset: TEM image of PbS QDs with an average size of 3.2 nm. b) Emission spectra of <sup>50</sup> PbS QDs in o-xylene and the in the nanocomposite film upon excitation at 532 nm.

# Lithographic properties of the QD-PIP nanocomposite – Sensor fabrication.

Design of novel multicomponent materials that combine unique optical properties of semiconducting nanoparticles with those s provided by the polymer matrix is of significant importance for

- the development of photonic nanostructures and more complex devices. In this sense, the successful miniaturization and application of this kind of nanocomposites critically depends on their capability of being patterned by means of lithographic or <sup>10</sup> other printing techniques.<sup>33</sup> In this work, bisazide-cyclized polyisoprene photoresist has been chosen as host matrix because this is a commercially available negative-tone resist formulated
- resists have high sensitivity, better adhesion to substrates and are normally used for fabrication of patterns above 1  $\mu$ m. Moreover, this type of negative tone photoresists suffers from swelling caused by the use of solvent-based developers like xylene or anisole. While the lateral swelling results in a kind of proximity effect, which can give rise to image distortions, vertical swelling

for UV lithography. Compared to the positive ones, negative

<sup>20</sup> does not affect the image accuracy and may significantly facilitate the diffusion of the analytes through the matrix. As a result, the time of sensing response to analyte-QDs interactions can be considerably reduced.

The fabrication of the chemo-sensor based on this novel <sup>25</sup> nanocomposite has been carried out by conventional UV lithography. The lithographic properties of the bisazide-cyclized polyisoprene photoresist are based on the crosslinking of cyclized poly(cis)isoprene by means of a bisazide-based photo active crosslinker. Upon exposure to 300-400 nm UV light, the bisazide

- <sup>30</sup> sensitizers decompose into nitrogen and highly reactive chemical intermediates, called nitrenes. These nitrenes do react actively with the cyclized polyisoprene to mainly form aziridine ring. As a result, polymer chains crosslink and three-dimensional structures are generated since the exposed areas are insoluble in the
- <sup>35</sup> developer. The cyclized polymer has a high glass transition temperature, good structural properties, and higher density and is formulated with o-xylene as a solvent.

Once the colloidal QDs are dispersed in o-xylene and mixed with the photoresist solution in o-xylene under mechanical stirring, the

- <sup>40</sup> solution is then spin-coated on a glass substrate at 2000 rpm for 30 s. In order to remove residual solvent and volatile components and to improve the adhesion a bake at 82 °C for 20 minutes is carried out to form a 1  $\mu$ m-thick film. The resulting nanocomposite film is then exposed to UV light at 200 mW/cm<sup>2</sup>
- <sup>45</sup> for 5 s using a test mask containing different patterns. For the development of the unexposed areas the developer is sprayed on the coated substrate for 10-20 s followed by a rinsing several times with isopropanol alcohol and blowing with air to dry the film. Finally, a hard-bake at 120 °C for 10 min is required to
- <sup>50</sup> remove residual solvents and to enhance the chemical stability of the layer. The concentration of QDs into the nanocomposite is the key parameter to optimize for a successful formulation of the photoresist because of two different reasons. First, the lithographic performance of the photoresist may be eventually

55 affected by the presence of QDs, especially at high concentrations. For instance, because QDs absorb strongly in the UV, a high QD concentration could disturb the UV absorption and photoreactions carried out by the photoactive compound (PAC) upon exposure, which would consequently affect the 60 crosslinking degree of polymer chains. Second, the PL efficiency of QDs embedded into resist is strongly affected by the concentration of QDs in the nanocomposite. For high concentration of QDs, a large part of emitted photons are reabsorbed by the same ODs decreasing significantly the PL 65 signal.<sup>32</sup> This is of specially importance for sensing, where a precise quantification of the emission intensity change in response to analyte bindings on the QDs is required. Therefore, the nanocomposite must be properly formulated to preserve as much as possible the lithographic properties of the photoresist 70 and minimize reabsorption of the luminescence. We formulated different nanocomposites with different OD wt. % and the same thickness and recorded the corresponding PL spectra (Fig. S5, ESI<sup>†</sup>). According to the criteria aforementioned, the optimum nanocomposite formulation was found to be 0.3 wt.% CdSe QD 75 and 5.0 wt. % bisazide-cyclyzed PIP in o-xylene, which corresponds to a final nanocomposite composition of 6 wt.% CdSe QD and 94 wt. % bis azide-cyclized PIP. For this formulation, the ratio of PL intensity to QD wt. % reaches its maximum value indicating that minimal reabsorption of the 80 luminescence takes place (Fig. S6, ESI<sup>†</sup>).

Fig. 3 shows several patterns of the CdSe-PIP nanocomposite fabricated on glass. We patterned various microstructures (interdigitates, solid squares and frameworks) with different feature sizes from 50 μm to 1 mm to test the lithographic sperformance of the nanocomposites. As can be observed, this formulation allows an accurate nanocomposite patterning preserving the intense PL of QDs. The resulting nanocomposite photoresist shows the same lithographic properties as the commercially available photoresist. PbS-based nanocomposite ophotoresists was also formulated with the same QD composition and rendered an excellent lithographic performance as in case of CdSe-base nanocomposite.



**Figure 3.** Optical microscope pictures of different CdSe-PIP nanocomposite structures on glass patterned by UV lithography: a) interdigitates, b) solid square, and c) framework.

## 5 Sensing in the visible range.

In this work, we test CdSe and PbS-PIP nanocomposite patterns fabricated by UV-lithography as a suitable platform for miniaturized chemosensors. Since the luminescence of QDs is very sensitive to any change on their surface, eventual

- <sup>10</sup> chemical or physical interactions between the target analyte and the QD surface may result in noticeable changes in the fluorescence emission parameters, such as the peak wavelength, intensity, and/or bandwidth. The QDs used in these studies are capped with oleate because this ligand can be
- <sup>15</sup> easily exchanged by other molecules or analytes and allows a good dispersion of QDs in o-xylene. Based on this fact, we expect that capping exchange of oleate with thiol or amine molecules may induce either the quenching or enhancement of the excitonic emission of the QDs embedded in the polymer <sup>20</sup> matrix.

Evaluation of the sensing capability of this nanocomposite was performed by exposing the nanocomposite patterns to vapours from aqueous solutions of two different volatile analytes: 2-mercaptoethanol (MET) and ethylenediamine

<sup>25</sup> (EDA) in a closed vessel of 130 mL in a thermostatic bath at 25°C. A given concentration of analyte will be in the vapour phase depending on the vapour pressure of the corresponding analyte once the liquid-vapour equilibrium is reached. This concentration can be estimated by the Raoult's Law assuming <sup>30</sup> that analyte-H<sub>2</sub>O behaves as an ideal solution.

Both thiols and diamines are well-known chelating ligands for coordination to heavy metals through S and N atoms, respectively, via their lone pairs of electrons.<sup>34</sup> By exposing the nanocomposite patterns to the analyte vapours, the <sup>35</sup> molecules can diffuse within the PIP-based matrix until they are adsorbed on the QD surface exchanging the oleate ligands. It is well known that bisazide-cyclized PIP photoresists suffer from swelling when they are exposed to organic solvents like o-xylene during the development. Even though this effect may 40 limit the resolution of the final patterns, it may significantly improve the diffusion of the analyte molecules through the matrix. As a result, analyte molecules can easily reach even those QDs located at the bottom of the patterns, thus improving the sensitivity and time response of the sensor. The 45 sensing studies were carried out with 1 cm-side square patterns of CdSe-PIP because this size allowed the use of a conventional optical setup to record the PL spectra.



50 Figure 4. Real time PL spectra response of miniaturized CdSe-PIP sensor upon exposure to vapour of a aqueous 10<sup>-4</sup> M solution of a) MET and b) EDA.

Fig. 4 shows the PL response of the nanocomposite for different exposure time to the vapours of a 10<sup>-4</sup> M solution of <sup>55</sup> MET and EDA. As one can see, interaction of the thiol and EDA molecules with the CdSe QD surface led to a significant change in the intensity and FWHM of the QD emission. In the case of MET (Fig. 4a), within the first 10 minutes, PL intensity has already decreased around 50 %. Sensor response <sup>60</sup> saturation is achieved after ca. 26 min of exposure showing a PL intensity around 9 %. In case of exposure to EDA vapours (Fig. 4b), we observed a slower quenching of the PL intensity in comparison to MET. Within the first 120 min the sensor PL decreases a 50% and saturates after ca. 190 min. From <sup>65</sup> Raoult's law, the mass concentration of MET and EDA in the vapour phase from a 10<sup>-4</sup> M solution is 5.8 and 58 ng/L

respectively.

The mechanism of PL quenching of QDs is related to the well-known hole-accepting properties of thiols, which can be demonstrated by the low oxidation potential of these 5 molecules. However, whereas the PL quenching effect can be well described within the dynamic quenching model and well predicted on the basis of a thiol oxidation potential and luminescent molecule HOMO energy when thiols interacts with small photoexcited luminescent molecules, interactions 10 of thiols with excited QDs is more difficult for a priory predictions of the interaction results. This is because thiol molecules have to be adsorbed on the nanocrystal surface before quenching an exciton localized inside а nanocrystal.<sup>35,36,37</sup> Such an adsorption results in formation of 15 deep surface states within a bandgap of a semiconductor nanocrystal and determines the static type of PL quenching.<sup>37,38</sup> Although the energetic position of such surface states is related to the thiol redox potential, it is not equal to the thiol redox potential due to complex interactions between

- <sup>20</sup> the counterparts of the QD-thiol complex. Therefore, the energy diagrams explaining QD PL quenching by hole acceptor molecules like thiols are usually of tentative character.
- As an example, we show such a diagram in Fig. 5. The data <sup>25</sup> for the diagram are taken from Ref. [35]. Indeed, oxidation potential of MET is higher in energy than the position of electronic valence band top for CdSe QDs that is the prerequisite for the formation of PL quenching deep surface state, after MET adsorption.



<sup>30</sup> **Figure 5.** Positions of valence and conduction band-edges of CdSe and PbS QDs with respect to vacuum and SHE in a comparison with redox potential of MET (adapted from Ref. 35).

- It is worth noting here that the literature about the influence of <sup>35</sup> EDA and related amines on the PL of CdSe and other QDs is contradictory. Slight PL intensity enhancement was observed for CdSe QDs in water under very low EDA concentrations (2x10<sup>-6</sup> M) that was followed by PL quenching under higher EDA concentrations.<sup>39</sup> PL intensity increase was observed for
- <sup>40</sup> CdTe QDs water solution under addition of EDA in mM concentrations.<sup>40</sup> Similar features were also found for QD PL quenching by other amines. For example, there are some interesting experiments on the CdSe PL response to n-

butylamine (n-BA) depending on the analyte concentrations:

- 45 whereas the PL intensity enhancement (saturation) is observed when n-BA concentration increase up to 1 mM,<sup>41</sup> a strong PL quenching is found for n-BA concentrations between 1 and 40 mM.<sup>42</sup> What is important here is that the n-BA induced quenching effect cannot be explained by a photoinduced 50 charge transfer reaction, namely by a hole transfer from excited CdSe QDs to n-BA, because oxidation potential of n-BA (>1.9 V vs NHE) is too high to provide electron transfer to the valence band edge of the CdSe QD (around 1.5 V). Therefore, the mechanism(s) of QDs PL quenching by amines 55 under conditions when concentration of the latters is higher than it is necessary for passivation of QD surface may be different from photoinduced hole acceptance by amines. There is an opinion in the literature that a universal reason is available for QD PL quenching by electron-donating 60 molecules like amines. The reason is the appearance of new local sites on a QD surface at the points of coordination of these molecules, which may act as deep traps. Thus, the PL is statically quenched that manifests itself as PL amplitude decrease without PL lifetime shortening.43,44
- <sup>65</sup> Fig. 6 shows the dependence of the CdSe nanocomposite PL intensity upon vapour exposure of EDA, MET and water as well as empirical exponential fitting curves, which describe the diffusion of both target analytes (Equation 1):

$$PL = PL_{\infty} + Aexp(-kt)$$
(1)

where PL is the PL integral intensity at a given time,  $PL_{\infty}$  is the final (saturated) PL, and k is the binding constant rate. We found  $k_{MET} = 1.47 \text{ ms}^{-1}$  and a  $PL_{\infty} = 1.2$  % for sensing of MET 75 vapour, and  $k_{EDA} = 0.11 \text{ ms}^{-1}$  and a  $PL_{\infty} = 2.7$  % were obtained for the PL decay after the chemisorption of EDA. We observed that the sensor response to vapour water is negligible.

The interaction between the analyte molecules and the CdSe QDs embedded in the polymer matrix is a strongly timedepending phenomenon, which is determined by the analyte mass transport and the subsequent chemical interaction time.<sup>45</sup> As aforementioned, this kind of polymer matrix suffers from swelling during the development, which causes an <sup>85</sup> enlargement of the inner free volume of the photoresist film. This effect is partially reversible and may facilitate the diffusion of the vapour molecules through the matrix to the QD surface. Therefore, diffusion of the analytes into the nanocomposite film takes place efficiently, allowing the <sup>90</sup> ligand exchange on the QD surface.

This kinetic constant depends on the affinity reaction between the analyte and the CdSe QD and also on the mass concentration of analyte in the vapour phase. The analyte binding rate constant of MET to CdSe is one order of <sup>95</sup> magnitud higher than that of EDA to CdSe despite the concentration of EDA is also one order of magnitud higher. This is expected since thiol molecules possess a higher affinity to the Cd(II) present on the surface of the QD in comparison to amines. As a result, capping exchange with <sup>100</sup> thiols takes place faster and the PL quenching reaches the maximum value at shorter exposure times and even with lower analyte concentrations.



**Figure 6.** Real time response of miniaturized CdSe-PIP sensor upon <sup>5</sup> the exposure to a 10<sup>-4</sup> M aqueous solution of MET and EDA (and the corresponding fitting curves) and water.

Fig. 7 presents the calibration curve of the sensor for a exposure time of 15 min, that is the sensor response to different analyte amounts of MET and EDA in vapour phase.

- <sup>10</sup> In Fig. S7 and S8 (ESI<sup>†</sup>) the corresponding calibration curves for longer exposure times such as 30 and 60 min are also shown. Calibration curves for analyte binding assays are generally characterized by a sigmoidal relationship between the sensor response and the analyte concentration. The four-
- <sup>15</sup> parameter logistic (4PL) function was used for fitting the concentration-response, because it is recognized as the reference standard for immunoassays such as ELISAs or dose-response curves.<sup>46</sup> The equation describing the 4PL function is:<sup>47</sup>

20

$$PL = PL_{\infty} + \frac{(PL_0 - PL_{\infty})}{1 + (C/C_{1/2})^s}$$
(2)

in which PL is the PL intensity response at a given analyte <sup>25</sup> concentration, PL<sub>∞</sub> is the response at a saturated analyte concentration, PL<sub>0</sub> is the response at zero analyte concentration, C is the analyte concentration, C<sub>1/2</sub> is the concentration of analyte necessary to produce a response of 50 %, and s is the slope at C<sub>1/2</sub> of the calibration curve.

- <sup>30</sup> As can be observed in Fig. 7, CdSe-PIP sensor exhibits a limit of detection (LOD) to MET and EDA around 10<sup>-3</sup> ng/L and 270 ng/L respectively, which is equivalent to an analyte mass of 0.1 pg and 32 ng. Additionally, in the Table S1 and S2 (ESI<sup>+</sup>) we show that the LOD of the sensor to MET and EDA
- <sup>35</sup> improves for longer exposures times. The number of CdSe QDs in a 1cm<sup>2</sup> sensor pattern with a film thickness of 1000 nm is estimated to be around 10<sup>14</sup> QDs, assuming a 6 wt.% of CdSe, a QD size of 2.5 nm and a cyclized PIP density of 0.99 g/cm<sup>3</sup>. From the LOD found for MET and EDA, we estimate
- <sup>40</sup> that the minimum sensor response is achieved for a ratio of analyte to CdSe QD around 0.4 and  $5x10^3$ . These ratios and therefore the LOD would be easily reduced just decreasing the

size and the film thickness of the sensor for a given exposure time. Obviously at the LOD the analyte binding takes place on <sup>45</sup> the most superficial QDs where the analyte-CdSe ratio is locally much higher. The maximum sensor response is achieved for MET and EDA concentrations around 100 and  $10^6$  ng/L and an estimated analyte:QD ratio around  $5 \times 10^3$  and  $10^{13}$  respectively.



**Figure 7.** PL decay response of CdSe-nanocomposite miniaturized sensor as a function of the mass concentration of EDA and MET in the vapour phase for an exposure time of 15 min. Inset: linear dependence and corresponding regression line of the sensor response.

- <sup>55</sup> The linear detection range for MET and EDA was determined to be over an analyte concentration of six and five orders of magnitude (inset of Fig. 7). The sensitivity for MET and EDA was determined to be 16.6 and 22.2 % from the slope of the linear regression of the calibration curve shown in the inset of Fig. 8.
- <sup>60</sup> The sensitivity is defined as the sensor response per logarithmic unit of analyte concentration. From the calibration curve, we can also determine the binding affinity (K<sub>A</sub>), which is the equilibrium binding constant and measures the tendency of the analyte to bind reversibly to the sensor. Under the assumption of a linear
  <sup>65</sup> relationship between sensor occupancy and response, binding affinity is equal to the inverse of C<sub>1/2</sub>.<sup>48, 49</sup> Thus, we found that a C<sub>1/2</sub> = 0.13±0.03 ng/L and K<sub>A</sub> = (7.75±1.80) ng/L for MET and. C<sub>1/2</sub> = 3294±375 ng/L and K<sub>A</sub> = (3.03±0.38)10<sup>-4</sup> ng/L for EDA. The higher the value of K<sub>A</sub>, the higher affinity between sensor
  <sup>70</sup> and analyte and the less analyte is required to achieve 50% occupancy of the sensor's binding sites. As expected CdSe-PIP sensor show much more affinity to MET than EDA.

### Sensing in the IR range.

Fig. 8a and 8b shows the time dependence of the PbS-PIP 75 sensor response to MET and EDA. The sensor composition was 6 wt.% PbS QD and 94 wt. % bis azide-cyclized PIP. We observed different sensor responses depending on the target analyte.



**Figure 8.** PL spectra response of PbS-PIP miniaturized sensor upon exposure to vapours of a) MET and b) EDA.

- 5 In case of EDA sensing (Fig. 8b), the PL intensity decreases with the exposure time. Here, the emission intensity drops totally after 10 min indicating that the capping exchange by EDA molecules on the surface was complete. However, binding of MET molecules to the PbS surface (Fig. 8a) affects
- <sup>10</sup> the luminescence properties in a remarkably different way from that observed for CdSe QDs. Here, attachment of MET molecules on the PbS QD surface results in a 6.5-fold enhancement of the PL intensity of the PbS QDs.

Fig. 9 shows the evolution of the PL intensity of a PbS-PIP <sup>15</sup> pattern for different exposure times to vapour of pure EDA, MET and water. Binding of MET and EDA molecules at the QD surface needs a determined incubation time to take place. Experimental data can be fitted to eq. 1. From this fit we found  $k_{MET} = 2.0 \text{ ms}^{-1}$  for sensing of MET vapour, and  $k_{EDT} =$ <sup>20</sup> 4.8 ms<sup>-1</sup>. We observed that the PbS-PIP sensor response to water vapour is negligible.

A possible explanation for the different response of CdSe and PbS QDs to MET could be found in the energetic position of the top of the valence band. The lower energetic position of

<sup>25</sup> the valence band for CdSe results in trapping of the photogenerated holes on the thiol molecule, thus quenching the luminescence, as aforementioned. For PbS, the fact that the valence band is located at higher energies with respect to the redox level of the thiol molecule makes the hole trapping <sup>30</sup> energetically unfavorable (Fig. 5). As a result, QY of PbS significantly increases due to the improvement of the quality of the QD surface passivation by thiols.



Figure 9. Real time response of PbS-PIP miniaturized sensor upon the exposure to MET, EDA and water (and the corresponding fitting <sup>35</sup> curves)

# Conclusions

In this work we have developed a patternable nanocomposite sensor based on luminescent CdSe (for the visible spectral range) and PbS (for the IR spectral range) QDs and a bisazide-40 cyclized polyisoprene photoresist (PIP) as host matrix. This QD-PIP nanocomposite combines the extraordinary optical properties of the QDs with the lithographic characteristics of the resist matrix. Both the optical properties of QDs and the lithographic performance of the photoresist are preserved after their incorporation of QDs into the photoresist. As a result, we

- <sup>45</sup> their incorporation of QDs into the photoresist. As a result, we accurately patterned different types of microstructures. The sensing capability of this QD-PIP nanocomposite was evaluated using 1 cm<sup>2</sup> square patterns as a disposable gas sensor for the detection of MET and EDA.
- <sup>50</sup> We showed chemosensing response of CdSe-PIP patterns against MET and EDA in vapour and found a LOD around 10<sup>-3</sup> and 270 ng/L respectively, this is an analyte mass of 0.1 pg and 15 ng. From the calibration curve, we determined that the binding affinity of MET to CdSe-PIP is around four orders of <sup>55</sup> magnitude higher than that of EDA. We also observed a linear sensing behaviour within a broad concentration range, which allows us to use CdSe-PIP as quantitative sensor for MET and EDA.

On the order hand, PbS-PIP nanocomposite shows different <sup>60</sup> sensor responses depending on the target analyte: whereas exposure of PbS-based nanocomposite to EDA led to quenching of the QD PL, exposure to MET molecules resulted in an 6.5-fold enhancement of the PL intensity. This different response of CdSe and PbS QDs to MET can be explained by <sup>65</sup> the difference in the energy of these QDs valence band top with respect to the redox level of the thiol molecule.

This work confirms that luminescent QD-PIP nanocomposite can form the basis of a fully disposable sensing platform technology to perform chemo-sensing of interest for several fields such as food industry, environmental monitoring and health because QD-PIP sensors can be fabricated and miniaturized with fast and large-scale fabrication process on <sup>5</sup> different substrates.

# Acknowledgements

This work was supported through the Spanish MCINN, Generalitat Valenciana and EU-NAVOLCHI Grants Nos. TEC2011-29120-C05-01, PROMETEOII/2014/059 and 10 288869 respectively.

# Notes and references

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- 1 F. S. Ligler, Anal. Chem. 2009, 81, 519.
- 2 X. D. Fan, I. M. White, S. I. Shopova, H. Y. Zhu, J. D. Suter, Y. Z. Sun, *Anal. Chim. Acta* 2008, **620**, 8.
- 3 M. R. Plata, A. M. Contento, A. Ríos, Sensors 2010, 10, 2511.
- 4 U. Resch-Genger, M. Grabolle, S. Cavaliere-Jaricot, R. Nitschke, T. Nann, *Nature Methods* 2008, 5, 763.
- 5 Y. Zhang, T. H. Wang, *Theranostics* 2012, **2**(7), 631.
- 6 Nanocrystal Quantum Dots, 2<sup>nd</sup> ed.; Klimov, V. I., Ed.; CRC Press: Boca Raton, FL, 2010.
- 7 M. F. Frasco and N. Chaniotakis, Sensors 2009, 9, 7266.
- 8 C. J. Murphy, Anal. Chem. 2002, 74, 520A.
- 9 H. Gordillo, I. Suárez, R. Abargues, P. Rodríguez-Cantó, S. Albert, J. P. Martínez-Pastor, *Journal of Nanomaterials* 2012, 2012, 9 pp.
- 10 V. M. Menon, S. Husaini, N. Okoye, N. V. Vallapil, J. Nanophoton. 2009, 3(1), 031608.
- 11 N. A. Bakar, M. M. Salleh, A. A. Umar, M. Yahaya, Adv. Nat. Sci: Nanosci. Nanotechnol. 2011, 2, 025011.
- 12 R. Liang, R. Tian, W Shi, Z. Liu, D. Yan, M. Wie, D. G. Evans, X. Duan, *Chem. Commun.* 2013, **49**, 969.
- 13 H. Wang, A. Yang, C. Sui, Optoelectronics Letters 2013, 9 (6), 421.
- 14 S. Li, M. M. Lin, M. S. Toprak, D. K. Kim, and M. Muhammed, *Nano Reviews* 2010, **1**, 5214.
- 15 A. C. Balazs, T. Emrick, T. P. Russell, *Science* 2006, **314(5802)**, 1107.
- 16 R. Abargues, J. Marqués-Hueso, J. Canet-Ferrer, E. Pedrueza, J. L. Valdés, E Jiménez, J. P. Martínez-Pastor, *Nanotechnology* 2008, 19, 355308.
- 17 C. Ingrosso, A. M. Panniello, R. Comparelli, M. L. Curri, and M. Striccoli, Materials 2010, 3, 1316.
- 18 R. Abargues, P. J. Rodriguez-Canto, S. Albert, I. Suarez, J. P. Martínez-Pastor, Mater. Chem. C 2014, 2, 908.
- 19 A. B. Dahlin, Sensors 2012, 12, 3018.
- 20 J. Marqués-Hueso, R. Abargues, J. L. Valdés, J. P. Martínez-Pastor, J. Mater. Chem. 2010, 20, 7436.
- 21 J. Marqués-Hueso, R. Abargues, J. Canet-Ferrer, S. Agouram, J. L. Valdés, J. P. Martínez-Pastor, *Langmuir* 2010, 26, 2825.

- 22 R. A. Potyrailo, A. M. Leach, C. M. Surman, ACS Comb Sci. 2012, 14 (3), 170.
- 23 A. Bueno, I. Suarez, R. Abargues, S. Sales, J. Martínez-Pastor, *IEEE Sensors Journal* 2012, **12 (10)**, 3069.
- 24 A. Y. Nazzal, L. Qu, X. Peng, and M. Xiao, *Nano Letters* 2003, 3(6), 819.
- Z. Zhao, M. Arrandalea, O. V. Vassiltsovab, M. A. Petrukhinab, M. A. Carpentera, *Sens. Actuators B* 2009, 141(1), 26.
- 26 O. V. Vassiltsovab, Z. Zhao, M. A. Petrukhinab, M. A. Carpenter, Sens. Actuators B 2007, 123, 522.
- 27 W. Knoben, P. Offermans, S. H. Brongersma, M. Crego-Calama, Sens. Actuators B 2010, 148, 307.
- 28 C. Ingrosso, V. Fakhfouri, M. Striccoli, A. Agostiano, A. Voigt, G. Gruetzner, M. L. Curri, and J. Brugger, *Adv. Funct. Mater.* 2007, 17, 2009.
- 29 L. Pang, K. Tetz, Y. Shen, C. Chen, and Y. Fainman, J. Vac. Sci. Technol. B 2005, 23(6), 2413.
- 30 W. W. Yu and X. Peng, Angew. Chem. Int. Ed. 2002, 41, 2368-2371.
- 31 W. W. Yu , L. Qu , W. Guo, X. Peng, Chem. Mater. 2003, 15(14), 2854.
- 32 I. Suárez, H. Gordillo, R. Abargues, S. Albert, J. Martínez-Pastor, Nanotechnology 2011, 22, 435202.
- 33 C. Ingrosso, A. M. Panniello, R. Comparelli, M. L. Curri, M. Striccoli, *Materials* 2010, 3, 1316.
- 34 R. A. Sperling, W. J. Parak, Phil. Trans. R. Soc. A 2010, 368, 1333.
- 35 S. F. Wuister, C. M. Donega, A. Meijerink, J. Phys. Chem. B 2004, 108, 17393.
- 36 M. Georgin, L. Carlini, S. E. Bradforth, J. L. Nadeau, *Phys. Chem. Chem. Phys.* 2013, **15**, 10418.
- 37 V. V. Breus, C. D. Heyes, G. U. Nienhaus, J. Phys. Chem. C 2007, 111, 18589.
- 38 Z. J. Jiang, V. Leppert, D. F. Kelley, J. Phys. Chem. C 2009, 113, 19161.
- 39 J. G. Liang, S. S. Zhang, X. P. Ai, X. H. Ji, Z. K. He, Spectrochim Acta A Mol Biomol Spectrosc. 2005, 61, 2974-8.
- 40 A. Mandal, N. Tamai, Chem. Phys. Lett. 2011, 507, 248.
- 41 S. N. Sharma, Z. S. Pillai, P. Kamat, J. Phys. Chem. B 2003, 107, 1088.
- 42 C. Landes, C. Burda. M. Braun, M. A. El-Sayed, J. Phys. Chem. B 2001, 105, 2981.
- 43 C. Landes, M. Braun, M. A. El-Sayed, J. Phys. Chem. B 2001, 105, 10554.
- 44 E. Zenkevich, T. Blaudeck, M. Heidernätsch, C. Von Borczyskowski, *Theor. Exp. Chem.* 2009, 45, 23.
- 45 R. Abargues, P. J. Rodriguez-Canto, S. Albert, I. Suarez, J. P. Martínez-Pastor, *Mater. Chem. C* 2014, 2, 908.
- 46 J. W. A. Findlay, W. C. Smith, J. W. Lee, G. D. Nordblom, I. Das, B. S. DeSilva, M. N. Khan and R. R. Bowsher, *J. Pharm. Biomed. Anal.* 2000, **21**, 1249–1273.
- 47 M. A. O'Connell, B. A. Belanger and P. D. Haaland, *Chemom. Intell. Lab. Syst.* 1993, 20, 97–114.
- 48 L. S. Jung, J. S. Shumaker-Parry, C. T. Campbell, S. S. Yee, M. H. J. Gelb, Am. Chem. Soc. 2000, **122**, 4177–4184.
- 49 T. Kenakin, Trends Pharmacol. Sci. 2004, 25, 186-192.